

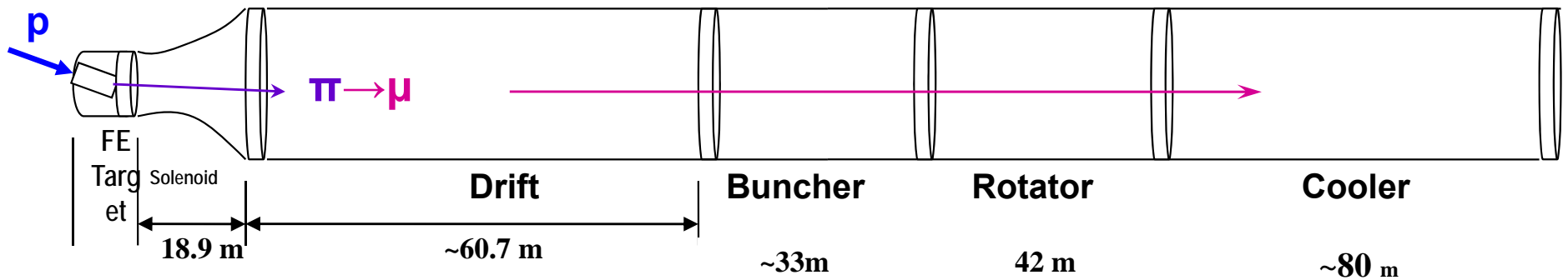
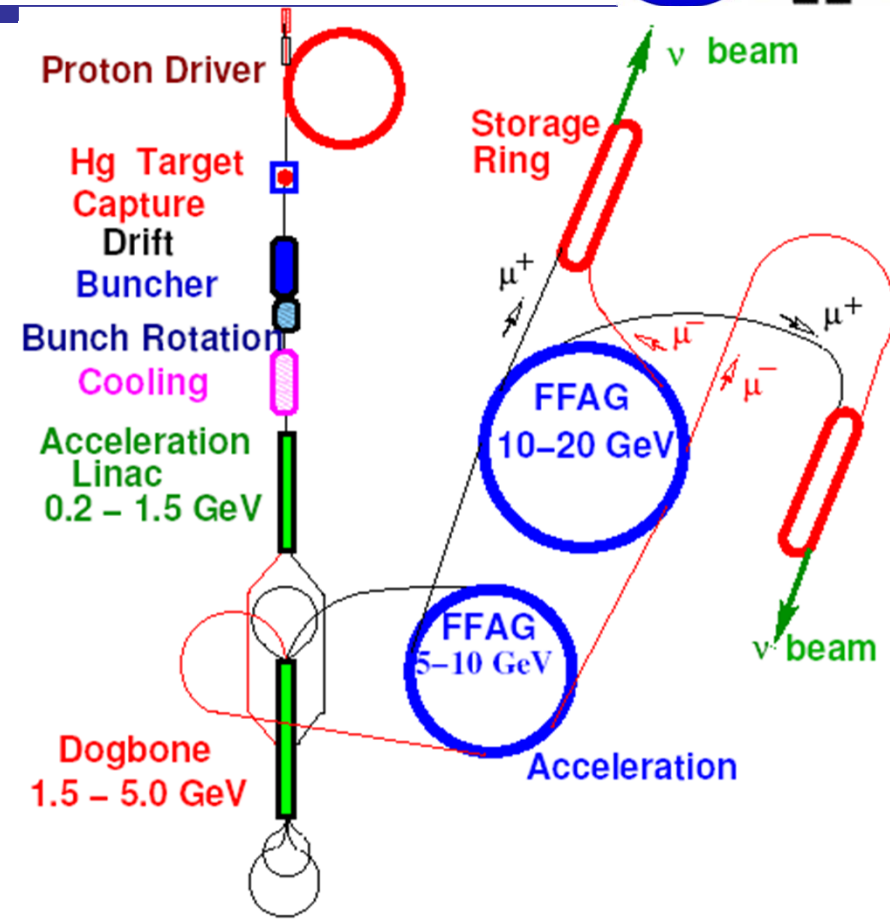
# Front End RF and Gas Cavities

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- Introduction
  - v-Factory Front end
  - rf/B limitation
- gas-filled rf
  - v-Factory →  $\mu^+ - \mu^-$  Collider
- Discussion

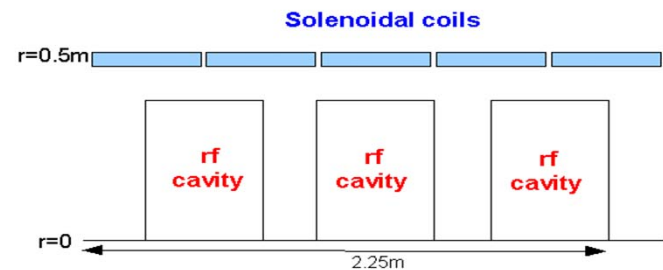


➤ Initial drift from target to buncher is 79.6m

- 18.9m (adiabatic ~20T to ~1.5T solenoid)
- 60.7m (1.5T solenoid)

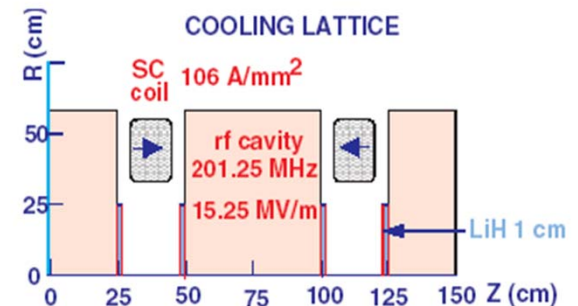
➤ Buncher rf – 33m

- 320 → 232 MHz
- 0 → 9 MV/m (2/3 occupancy)
- B=1.5T



➤ Rotator rf -42m

- 232 → 202 MHz
- 12 MV/m (2/3 occupancy)
- B=1.5T



➤ Cooler (50 to 90m)

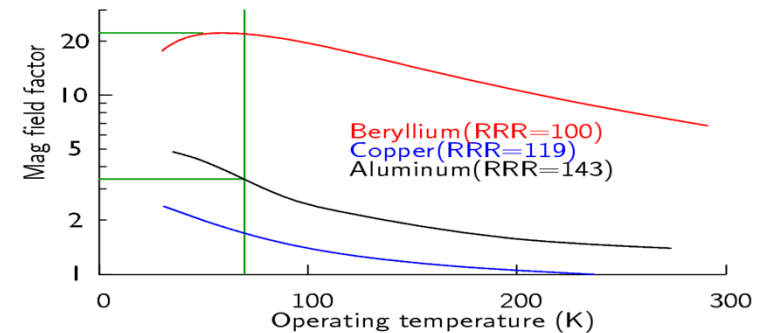
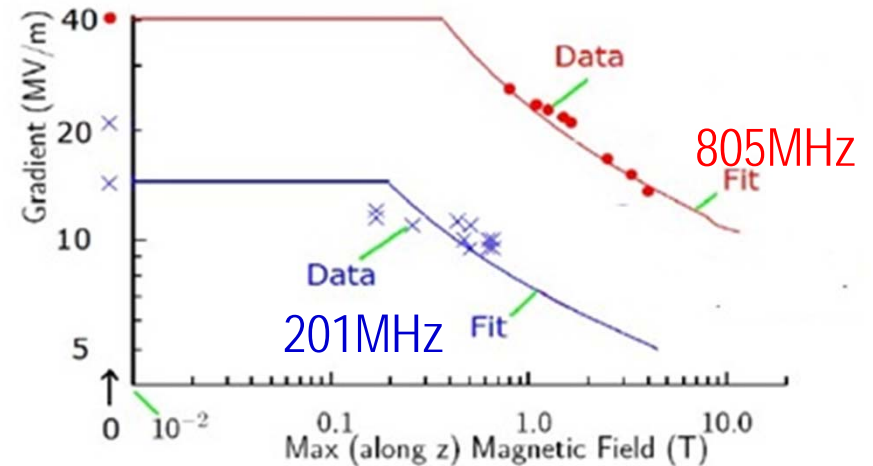
- ASOL lattice,  $P_0 = 232\text{MeV/c}$ ,
- Baseline has  $\sim 16\text{MV/m}$ , 2  $1.1\text{ cm}$  LiH absorbers /cell

## $V'_{rf}$ may be limited in B-fields

- 800 MHz pillbox cavity
- 200 MHz pillbox test (different B)
- NF needs up to  $\sim 1.5T$ , 12 MV/m
  - More for cooling

## Potential strategies:

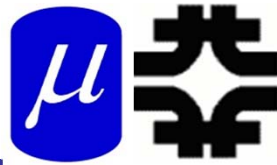
- Use Be Cavities (Palmer)
- Use lower fields ( $V'$ , B)
  - $< 10MV/m$  at 1.5T?
    - Need variant for cooling ?
- Cooling channel variants
  - Use gas-filled rf cavities
  - Insulated rf cavities
  - Bucked coils (Alekou)
  - Magnetic shielding



## Need More Experiments !

- at  $\sim 200MHz$
- with  $B \sim B_{\text{frontend}}$

# H<sub>2</sub> gas-filled rf in front end cooling section

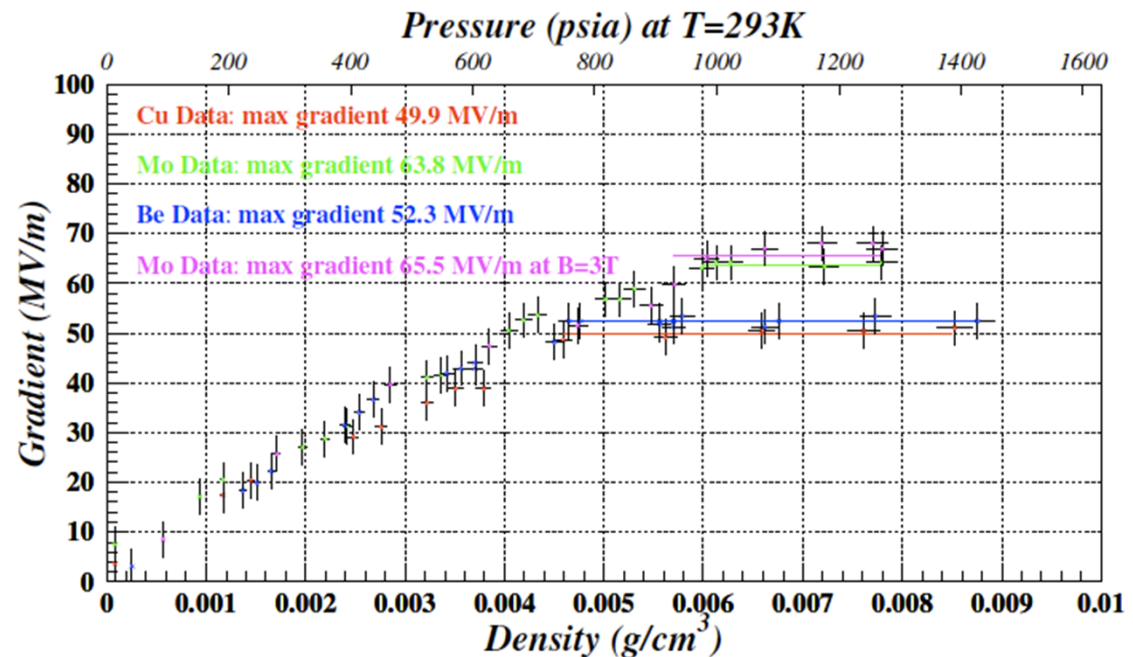
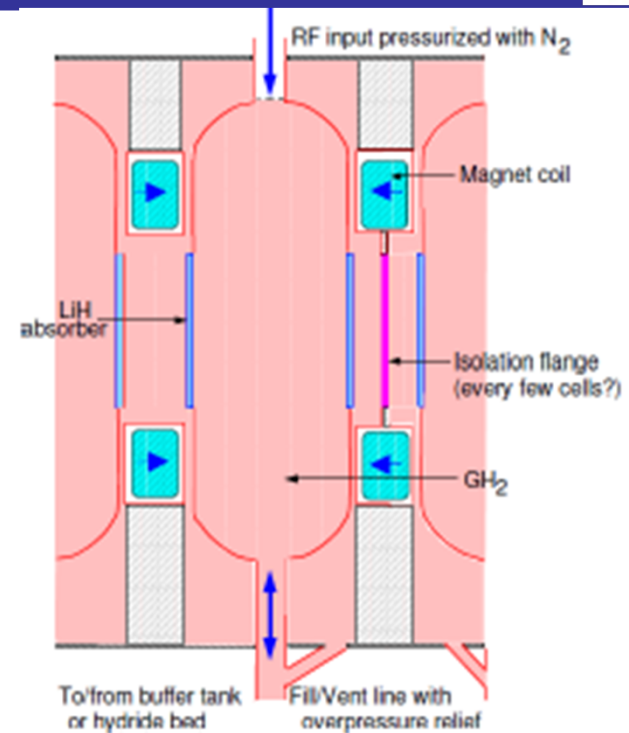


## ➤ Scenario I

- include only enough gas to prevent breakdown - ~20 atm
  - $E/P = \sim 9.9 \text{ V/cm/Torr}$

## ➤ Scenario II

- include gas density to provide all cooling
  - ~100atm
    - $E/P \sim 2$



- ionization produces electrons along the beam path
  - $\sim 1 e^- / 35\text{eV}$  of energy loss (?)
  - $\mu$  in  $\text{H}_2$  –  $4.1 \text{ MeV/gm/cm}^2$ 
    - At Liquid density (0.0708)  $8290 e^- / \text{cm}$
    - At 1 atm  $\sim 9.82 e^- / \text{cm}$
    - At 20 atm  $\sim 196 e^- / \text{cm}$
    - At 100atm  $\sim 980 e^- / \text{cm}$
  - Electrons have low energy collisions with  $\text{H}_2$  in electric field, equilibrating to a meant velocity proportional
  
- baseline 200 MHz cavity is 0.5m long
  - $10^4 e^- / \text{cavity}$  per  $\mu$  at 20 atm
  - $5 \times 10^4 e^- / \text{cavity}$  at 100 atm

- Electrons have low energy collisions with H<sub>2</sub> in electric field, equilibrating to a mean velocity proportional to  $x=E/P$  (Hylleraas)

- $$\vec{v}(x) = \mu_H(x)\vec{x} \times 5.9 \times 10^5 \text{ m/s}$$

- $$\mu_H(x) \cong 0.0172x^{-0.53}(1 - 0.024x^{0.71})^{-1.75}$$

- $x$  is in V/cm/Torr

- Electrons extract energy from the cavity from  $eV \cdot E$

- Energy loss per rf cycle:

- $$\Delta E \cong \int_{-\frac{\pi}{2}}^{\frac{\pi}{2}} e\mu_H(x \cos \theta)x \cos \theta 5.935 \times 10^5 E_{rf} \cos \theta d\theta$$

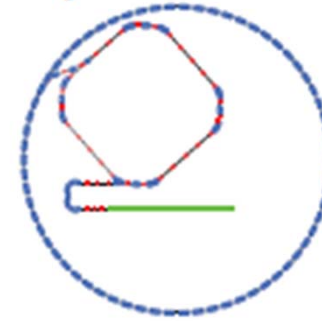
- assumes electron velocity tracks Electric field through rf cycle

- $\Delta E = 2.6 \times 10^{-16} \text{ J (} x=10 \text{) or } \Delta E = 1.1 \times 10^{-16} \text{ J (} x=2 \text{)}$

- 16MV/m, 200 MHz

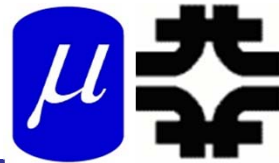
- Muon + intensity depends on proton production intensity
  - Assume 4MW – 8GeV
  - $N_p \approx 3 \times 10^{15}/s$
- 60 Hz scenario
  - $\sim 5 \times 10^{13}/bunch$
  - Each bunch produces train of secondary bunches
    - $\sim 20$  bunches,  $0.2 \mu/p$
    - $\sim 5 \times 10^{11}$  charges/bunch
- 50 Hz, 5 bunches/cycle
  - $\sim 1.2 \times 10^{13}/bunch$ 
    - $\sim 10^{11}$  charges/bunch

FFAG/synchrotron option

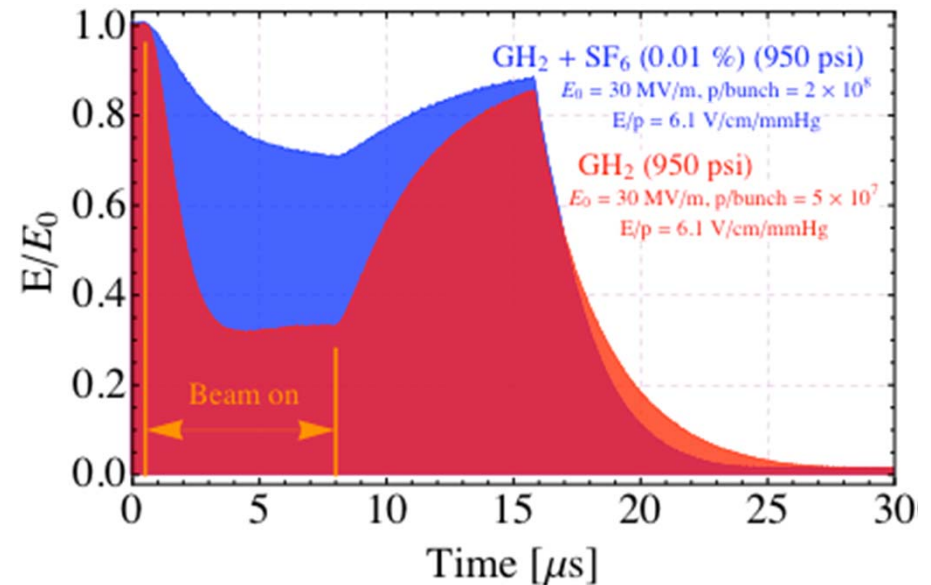




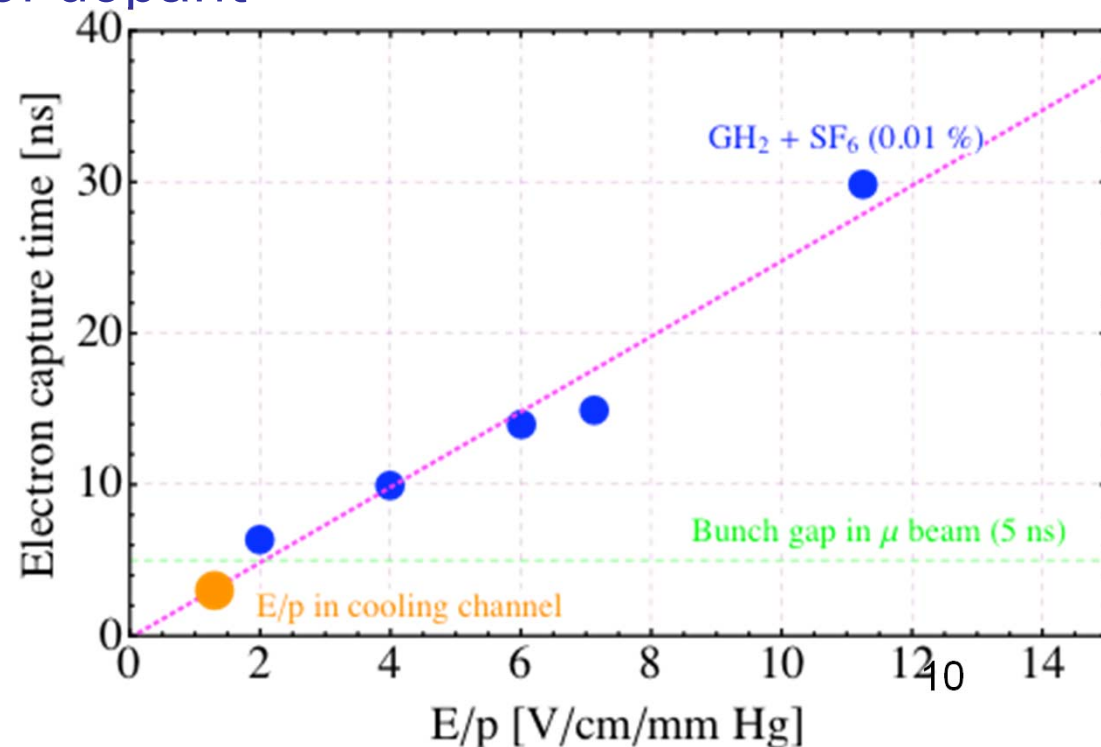
# Effect in rf cavity:



- Baseline stored energy in 1 rf cavity is 158J
  - $5 \times 10^{11} \times 10^4 \times 2.6 \times 10^{-16}$  J/cavity/bunch/rf cycle
    - **~1.3J/rf cycle**
  - but we have ~20 bunches
    - **~26J/rf cycle**
  - after 20 rf cycles
    - **lose 200J**
  
- Assumes no recombination/loss of electrons over 100ns
  - (20 cycles)
  
- 100 atm scenario is only a factor of 2 worse.



- Fewer p/bunch
  - 50Hz, 5 bunches, 2MW scenario reduces by factor of  $\sim 10$ 
    - manageable
- Must reduce free electron lifetime in gas
  - if  $< \sim 10\text{ns}$  problem is manageable
  - $< \sim 200\text{ns}$  (KY)
  - Is smaller with small amount of dopant



- **Gas-filled rf in v-Factory Front end Cooling could have large beam-loading effect**
  - Require electron recombination within  $\sim 20\text{ns}$
  - Can obtain this with dopant in  $\text{H}_2$
  
- **Gas-Filled rf can be used in Front end**
  - is not trouble-free however